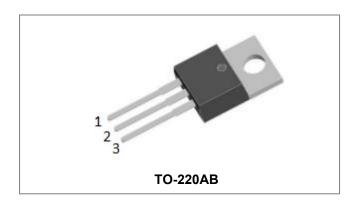






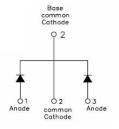
# **MBR60100CT SCHOTTKY RECTIFIER**



### **Features**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- · mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- · Reverse battery protection

## **Maximum Ratings:**

| Characteristics  | Symbol   | Condition                                       | Max.                          | Units |
|--|--|---|-------------------------------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | -   | 100                           | V     |
| Average Rectified Forward Current  | I <sub>F (AV)</sub>                                    | 50% duty cycle @Tc=135°C, rectangular wave form | 30(Per Leg)<br>60(Per Device) | Α     |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg)                                   | I <sub>FSM</sub>                                       | 8.3ms, Half Sine pulse                          | 280                           | Α     |

#### **Electrical Characteristics:**

| Characteristics                | Symbol          | Condition  | Тур. | Max.   | Units |
|--------------------------------|-----------------|--|------|--------|-------|
| Forward Voltage Drop(Per Leg)* | $V_{F1}$        | @ 30A, Pulse, T <sub>J</sub> = 25°C                | 0.85 | 0.90   | V     |
|                                | $V_{F2}$        | @ 30A, Pulse, T <sub>J</sub> = 125°C               | 0.76 | 0.81   | V     |
| Reverse Current(Per Leg)*      | I <sub>R1</sub> | $@V_R = \text{rated } V_R$<br>$T_J = 25^{\circ}C$  | 0.01 | 1.0    | mA    |
|                                | I <sub>R2</sub> | $@V_R = \text{rated } V_R$<br>$T_J = 125^{\circ}C$ | 8    | 20     | mA    |
| Junction Capacitance(Per Leg)  | Ст              | $@V_R = 5V, T_C = 25^{\circ}C, f_{SIG} = 1MHz$     | 400  | 800    | pF    |
| Voltage Rate of Change         | dv/dt           | -  | -    | 10,000 | V/s   |

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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## **Thermal-Mechanical Specifications:**

| Characteristics                                  | Symbol Condition  |                                      | Specification | Units |
|--|-------------------|--------------------------------------|---------------|-------|
| Junction Temperature                             | TJ                | -                                    | -55 to +150   | °C    |
| Storage Temperature                              | T <sub>stg</sub>  | -                                    | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Case      | R <sub>θCS</sub>  | Mounting surface, smooth and greased | 0.24          | °C/W  |
| Typical Thermal Resistance Junction to Ambient   | R <sub>θJA</sub>  | DC operation                         | 50            | °C/W  |
| Typical Thermal<br>Resistance, Case to Heat Sink | R <sub>0</sub> CS | Mounting surface, smooth and greased | 0.50          | °C/W  |
| Approximate Weight                               | wt                | -                                    | 2             | g     |
| Case Style                                       | TO-220AB          |                                      |               |       |

## **Ratings and Characteristics Curves**

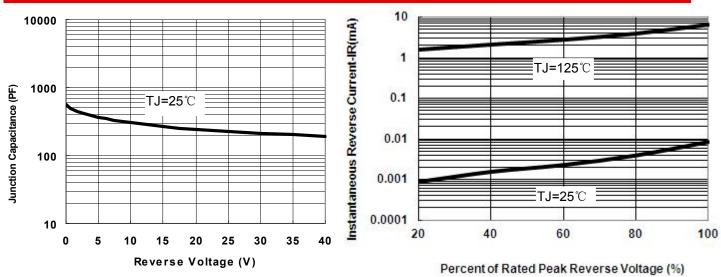


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

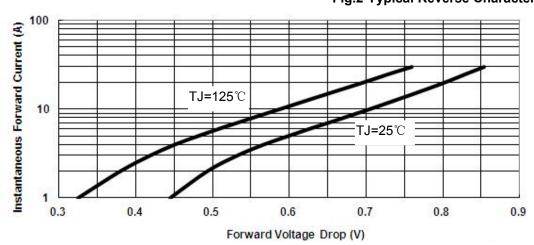


Fig.3-Typical Instantaneous Forward Voltage Characteristics

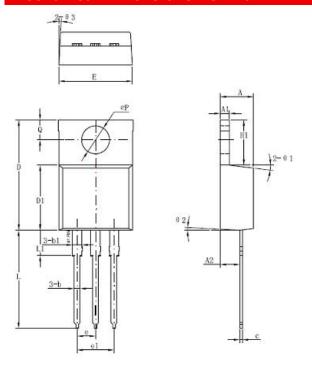
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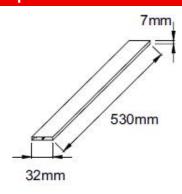


### **Mechanical Dimensions TO-220AB**

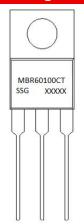


|        | Dimensions in |         |       |
|--------|---------------|---------|-------|
| Symbol | millimeters   |         |       |
|        | Min           | Typical | Max   |
| Α      | 4.42          | 4.57    | 4.72  |
| A1     | 1.17          | 1.27    | 1.37  |
| A2     | 2.52          | 2.69    | 2.89  |
| b      | 0.71          | 0.81    | 0.96  |
| b1     | 1.17          | 1.27    | 1.37  |
| С      | 0.31          | 0.38    | 0.61  |
| D      | 14.94         | 15.24   | 15.54 |
| D1     | 8.85          | 9.00    | 9.15  |
| E      | 10.01         | 10.16   | 10.31 |
| е      |               | 2.54    |       |
| e1     | 4.98          | 5.06    | 5.18  |
| H1     | 6.04          | 6.24    | 6.44  |
| L      | 12.7          | 13.56   | 13.80 |
| L1     | 3.56          | 3.5     | 3.96  |
| ФР     | 3.74          | 3.84    | 4.04  |
| Q      | 2.54          | 2.74    | 2.94  |
| Θ1     |               | 7°      |       |
| Θ2     |               | 3°      |       |
| Θ3     |               | 4°      |       |

## **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 60 = Forward Current (60A) 100 = Reverse Voltage(100V) CT = Configuration

CT = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

## **Ordering Information**

| Device     | Package            | Shipping     |  |
|------------|--------------------|--------------|--|
| MBR60100CT | TO-220AB (Pb-Free) | 50 pcs/ tube |  |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

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